



**DEPARTMENT OF PHYSICS
UNIVERSITY OF PUNE
PUNE 411007**

A D V E R T I S E M E N T

Applications are invited on plain paper for the following post on purely temporary basis under the research scheme entitled “**Establishment of a dual chamber Hot Wire Chemical Vapor Deposition (HW-CVD) technique and synthesis of intrinsic and doped hydrogenated microcrystalline silicon ($\mu\text{c-Si:H}$) and evaluation of their opto-electronic properties for photovoltaic applications**’ funded by Department of Science and Technology, Government of India, New Delhi. The details of the post are as follows:

Name of post	: Junior Research Fellow (JRF)
Number of post	: 01 (One)
Fellowship/Salary	: Rs. 12,000-12,000-14,000/- + HRA per month
Duration	: 03 (Three) years (2008- 2011)
Essential Qualifications	: M. Sc. in Physics/ M. Sc. in Electronic Science or equivalent with First or Higher Second Class
Principal Investigator	: Dr. S. R. Jadkar
Principal Co-Investigator	: Dr. S. W. Gosavi

Application with complete bio data along with attested copies of all the necessary certificates should reach to **Dr. S. R. Jadkar or Dr. S. W. Gosavi, Department of Physics, University of Pune, Pune 411007** on or before **21st April 2008**. All the applicants must appear for an interview on **29th April 2008** at 11:00 a m at the Department of Physics, University of Pune. No separate call letter for the interview will be issued. No TA/DA will be given to the candidates for attending interview.

15th March, 2008

**Registrar
University of Pune
Pune 411007**